

Contents

1 Metals: the Drude and Sommerfeld models	1
1.1 Introduction	1
1.2 What do we know about metals?	1
1.3 The Drude model	2
1.3.1 Assumptions	2
1.3.2 The relaxation-time approximation	3
1.4 The failure of the Drude model	4
1.4.1 Electronic heat capacity	4
1.4.2 Thermal conductivity and the Wiedemann–Franz ratio	4
1.4.3 Hall effect	6
1.4.4 Summary	7
1.5 The Sommerfeld model	7
1.5.1 The introduction of quantum mechanics	7
1.5.2 The Fermi–Dirac distribution function	9
1.5.3 The electronic density of states	9
1.5.4 The electronic density of states at $E \approx E_F$	10
1.5.5 The electronic heat capacity	11
1.6 Successes and failures of the Sommerfeld model	13
2 The quantum mechanics of particles in a periodic potential: Bloch's theorem	16
2.1 Introduction and health warning	16
2.2 Introducing the periodic potential	16
2.3 Born–von Karman boundary conditions	17
2.4 The Schrödinger equation in a periodic potential	18
2.5 Bloch's theorem	19
2.6 Electronic bandstructure	20
3 The nearly-free electron model	23
3.1 Introduction	23
3.2 Vanishing potential	23
3.2.1 Single electron energy state	23
3.2.2 Several degenerate energy levels	24
3.2.3 Two degenerate free-electron levels	24
3.3 Consequences of the nearly-free-electron model	26
3.3.1 The alkali metals	27
3.3.2 Elements with even numbers of valence electrons	27
3.3.3 More complex Fermi surface shapes	29

4	The tight-binding model	32
4.1	Introduction	32
4.2	Band arising from a single electronic level	32
4.2.1	Electronic wavefunctions	32
4.2.2	Simple crystal structure.	33
4.2.3	The potential and Hamiltonian	33
4.3	General points about the formation of tight-binding bands	35
4.3.1	The group IA and IIA metals; the tight-binding model viewpoint	36
4.3.2	The Group IV elements	36
4.3.3	The transition metals	37
5	Some general points about bandstructure	41
5.1	Comparison of tight-binding and nearly-free-electron bandstructure	41
5.2	The importance of \mathbf{k}	42
5.2.1	$\hbar\mathbf{k}$ is <i>not</i> the momentum	42
5.2.2	Group velocity	42
5.2.3	The effective mass	42
5.2.4	The effective mass and the density of states	43
5.2.5	Summary of the properties of \mathbf{k}	44
5.2.6	Scattering in the Bloch approach	45
5.3	Holes	45
5.4	Postscript	46
6	Semiconductors and Insulators	49
6.1	Introduction	49
6.2	Bandstructure of Si and Ge	50
6.2.1	General points	50
6.2.2	Heavy and light holes	51
6.2.3	Optical absorption	51
6.2.4	Constant energy surfaces in the conduction bands of Si and Ge	52
6.3	Bandstructure of the direct-gap III-V and II-VI semiconductors	53
6.3.1	Introduction	53
6.3.2	General points	53
6.3.3	Optical absorption and excitons	54
6.3.4	Excitons	55
6.3.5	Constant energy surfaces in direct-gap III-V semiconductors	56
6.4	Thermal population of bands in semiconductors	56
6.4.1	The law of mass action	56
6.4.2	The motion of the chemical potential	58
6.4.3	Intrinsic carrier density	58
6.4.4	Impurities and extrinsic carriers	59
6.4.5	Extrinsic carrier density	60
6.4.6	Degenerate semiconductors	62

6.4.7	Impurity bands	62
6.4.8	Is it a semiconductor or an insulator?	62
6.4.9	A note on photoconductivity	63
7	Bandstructure engineering	65
7.1	Introduction	65
7.2	Semiconductor alloys	65
7.3	Artificial structures	66
7.3.1	Growth of semiconductor multilayers	66
7.3.2	Substrate and buffer layer	68
7.3.3	Quantum wells	68
7.3.4	Optical properties of quantum wells	69
7.3.5	Use of quantum wells in opto-electronics	70
7.3.6	Superlattices	71
7.3.7	Type I and type II superlattices	71
7.3.8	Heterojunctions and modulation doping	73
7.3.9	The envelope-function approximation	74
7.4	Band engineering using organic molecules	75
7.4.1	Introduction	75
7.4.2	Molecular building blocks	75
7.4.3	Typical Fermi surfaces	77
7.4.4	A note on the effective dimensionality of Fermi-surface sections	78
7.5	Layered conducting oxides	78
7.6	The Peierls transition	81
8	Measurement of bandstructure	85
8.1	Introduction	85
8.2	Lorentz force and orbits	85
8.2.1	General considerations	85
8.2.2	The cyclotron frequency	85
8.2.3	Orbits on a Fermi surface	87
8.3	The introduction of quantum mechanics	87
8.3.1	Landau levels	87
8.3.2	Application of Bohr's correspondence principle to arbitrarily-shaped Fermi surfaces in a magnetic field	89
8.3.3	Quantisation of the orbit area	90
8.3.4	The electronic density of states in a magnetic field	91
8.4	Quantum oscillatory phenomena	91
8.4.1	Types of quantum oscillation	93
8.4.2	The de Haas-van Alphen effect	94
8.4.3	Other parameters which can be deduced from quantum oscillations	96
8.4.4	Magnetic breakdown	97
8.5	Cyclotron resonance	97
8.5.1	Cyclotron resonance in metals	98
8.5.2	Cyclotron resonance in semiconductors	98
8.6	Interband magneto-optics in semiconductors	100

8.7	Other techniques	102
8.7.1	Angle-resolved photoelectron spectroscopy (ARPES)	103
8.7.2	Electroreflectance spectroscopy	104
8.8	Some case studies	105
8.8.1	Copper	105
8.8.2	Recent controversy: Sr_2RuO_4	106
8.8.3	Studies of the Fermi surface of an organic molecular metal	106
8.9	Quasiparticles: interactions between electrons	112
9	Transport of heat and electricity in metals and semiconductors	117
9.1	A brief digression; life without scattering would be difficult!	117
9.2	Thermal and electrical conductivity of metals	119
9.2.1	Metals: the 'Kinetic theory' of electron transport	119
9.2.2	What do τ_σ and τ_κ represent?	120
9.2.3	Matthiessen's rule	122
9.2.4	Emission and absorption of phonons	122
9.2.5	What is the characteristic energy of the phonons involved?	123
9.2.6	Electron-phonon scattering at room temperature	123
9.2.7	Electron-phonon scattering at $T \ll \theta_D$	123
9.2.8	Departures from the low temperature $\sigma \propto T^{-5}$ dependence	124
9.2.9	Very low temperatures and/or very dirty metals	124
9.2.10	Summary	125
9.2.11	Electron-electron scattering	125
9.3	Electrical conductivity of semiconductors	127
9.3.1	Temperature dependence of the carrier densities	127
9.3.2	The temperature dependence of the mobility	128
9.4	Disordered systems and hopping conduction	129
9.4.1	Thermally-activated hopping	129
9.4.2	Variable range hopping	130
10	Magnetoresistance in three-dimensional systems	133
10.1	Introduction	133
10.2	Hall effect with more than one type of carrier	133
10.2.1	General considerations	133
10.2.2	Hall effect in the presence of electrons and holes	135
10.2.3	A clue about the origins of magnetoresistance	135
10.3	Magnetoresistance in metals	135
10.3.1	The absence of magnetoresistance in the Sommerfeld model of metals	135
10.3.2	The presence of magnetoresistance in real metals	137
10.3.3	The use of magnetoresistance in finding the Fermi-surface shape	138
10.4	The magnetophonon effect	139

11	Magnetoresistance in two-dimensional systems and the quantum Hall effect	143
11.1	Introduction: two-dimensional systems	143
11.2	Two-dimensional Landau-level density of states	144
11.2.1	Resistivity and conductivity tensors for a two-dimensional system	145
11.3	Quantisation of the Hall resistivity	147
11.3.1	Localised and extended states	148
11.3.2	A further refinement— spin splitting	148
11.4	Summary	149
11.5	The fractional quantum Hall effect	150
11.6	More than one subband populated	151
12	Inhomogeneous and hot carrier distributions in semiconductors	154
12.1	Introduction: inhomogeneous carrier distributions	154
12.1.1	The excitation of minority carriers	154
12.1.2	Recombination	155
12.1.3	Diffusion and recombination	155
12.2	Drift, diffusion and the Einstein equations	156
12.2.1	Characterisation of minority carriers; the Shockley–Haynes experiment	156
12.3	Hot carrier effects and ballistic transport	158
12.3.1	Drift velocity saturation and the Gunn effect	158
12.3.2	Avalanching	160
12.3.3	A simple resonant tunnelling structure	160
12.3.4	Ballistic transport and the quantum point contact	161
A	Useful terminology in condensed matter physics	165
A.1	Introduction	165
A.2	Crystal	165
A.3	Lattice	165
A.4	Basis	165
A.5	Physical properties of crystals	166
A.6	Unit cell	166
A.7	Wigner–Seitz cell	167
A.8	Designation of directions	167
A.9	Designation of planes; Miller indices	168
A.10	Conventional or primitive?	169
A.11	The 14 Bravais lattices	171
B	Derivation of density of states in k-space	172
B.1	Introduction	172
B.1.1	Density of states	173
B.1.2	Reading	174
C	Derivation of distribution functions	175
C.1	Introduction	175
C.1.1	Bosons	178
C.1.2	Fermions	178
C.1.3	The Maxwell–Boltzmann distribution function	178
C.1.4	Mean energy and heat capacity of the classical gas	179

D Phonons	181
D.1 Introduction	181
D.2 A simple model	182
D.2.1 Extension to three dimensions	183
D.3 The Debye model	185
D.3.1 Phonon number	187
D.3.2 Summary; the Debye temperature as a useful energy scale in solids	188
D.3.3 A note on the effect of dimensionality	188
E The Bohr model of hydrogen	191
E.1 Introduction	191
E.2 Hydrogenic impurities	192
E.3 Excitons	192
F Experimental considerations in measuring resistivity and Hall effect	194
F.1 Introduction	194
F.2 The four-wire method	194
F.3 Sample geometries	196
F.4 The van der Pauw method.	197
F.5 Mobility spectrum analysis	198
F.6 The resistivity of layered samples	198
G Canonical momentum	200
H Superconductivity	201
H.1 Introduction	201
H.2 Pairing	201
H.3 Pairing and the Meissner effect	203
I List of selected symbols	205
J Solutions and additional hints for selected exercises	209
Index	217